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APPLICATION NO.	F	ILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
09/842,403	09/842,403 04/26/2001		Shinichi Ito	04329.2566	9090
22852	7590	12/04/2002			
FINNEGAN, HENDERSON, FARABOW, GARRETT & DUNNER LLP 1300 I STREET, NW				EXAMINER	
				ESTRADA, MICHELLE	
	WASHINGTON, DC 20006			ART UNIT	PAPER NUMBER
				ARTONII	PATER NUMBER
				2823	
				DATE MAILED: 12/04/2002	

Please find below and/or attached an Office communication concerning this application or proceeding.

	Application No.					
	Application No.	Applicant(s)				
Office Action Summary	09/842,403	ITO ET AL.				
Office Action Summary	Examiner	Art Unik				
The MANUALC DATE of this communication	Michelle Estrada	2823				
Th MAILING DATE of this communication a	app ars on the cover sheet with t	he correspondenc addr ss				
A SHORTENED STATUTORY PERIOD FOR REI THE MAILING DATE OF THIS COMMUNICATION - Extensions of time may be available under the provisions of 37 CFR after SIX (6) MONTHS from the mailing date of this communication. - If the period for reply specified above is less than thirty (30) days, a - If NO period for reply is specified above, the maximum statutory peri - Failure to reply within the set or extended period for reply will, by sta - Any reply received by the Office later than three months after the ma earned patent term adjustment. See 37 CFR 1.704(b). Status	N. 1.136(a). In no event, however, may a reply life reply within the statutory minimum of thirty (30 od will apply and will expire SIX (6) MONTHS to the cause the application to become ABAND	be timely filed) days will be considered timely. from the mailing date of this communication.				
1) Responsive to communication(s) filed on 2	7 September 2002 .					
	This action is non-final.					
3) Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under <i>Ex parte Quayle</i> , 1935 C.D. 11, 453 O.G. 213. Disposition of Claims						
4)⊠ Claim(s) <u>1-23</u> is/are pending in the application.						
4a) Of the above claim(s) 19 and 21 is/are withdrawn from consideration.						
5) Claim(s) is/are allowed.						
6)⊠ Claim(s) <u>1-18,20,22 and 23</u> is/are rejected.						
7) Claim(s) is/are objected to.						
8) Claim(s) are subject to restriction and/or election requirement.						
Application Papers						
9) The specification is objected to by the Examiner.						
10) The drawing(s) filed on is/are: a) accepted or b) objected to by the Examiner.						
Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).						
11) The proposed drawing correction filed on is: a) ☐ approved b) ☐ disapproved by the Examiner.						
If approved, corrected drawings are required in reply to this Office action.						
12) The oath or declaration is objected to by the Examiner.						
Priority under 35 U.S.C. §§ 119 and 120						
13) Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f).						
a)⊠ All b)□ Some * c)□ None of: 						
1. Certified copies of the priority documents have been received.						
2. Certified copies of the priority documents have been received in Application No						
 3. Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)). * See the attached detailed Office action for a list of the certified copies not received. 						
14) Acknowledgment is made of a claim for dome						
_ a) \square The translation of the foreign language p	provisional application has been	received.				
15) Acknowledgment is made of a claim for dome Attachment(s)	estic priority under 35 U.S.C. §§ 1	120 and/or 121.				
1) Notice of References Cited (PTO-892) 2) Notice of Draftsperson's Patent Drawing Review (PTO-948) 3) Information Disclosure Statement(s) (PTO-1449) Paper No(s)	5) Notice of Inform	nary (PTO-413) Paper No(s) nal Patent Application (PTO-152)				
J.S. Patent and Trademark Office PTO-326 (Rev. 04-01) Office	Action Summary	Part of Paper No. 8				

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DETAILED ACTION

Election/Restrictions

Applicant's election without traverse of Group I (claims 1-18, 20, 22 and 23) in Paper No. 7 is acknowledged.

Information Disclosure Statement

The information disclosure statement filed 4/26/01 fails to comply with 37 CFR 1.98(a)(2), which requires a legible copy of each U.S. and foreign patent; each publication or that portion which caused it to be listed; and all other information or that portion which caused it to be listed. It has been placed in the application file, but the information referred to therein has not been considered. Copies of "Other Documents" not found in application.

The information disclosure statement filed 4/26/02 fails to comply with 37 CFR 1.98(a)(3) because it does not include a concise explanation of the relevance, as it is presently understood by the individual designated in 37 CFR 1.56(c) most knowledgeable about the content of the information, of each patent listed that is not in the English language. It has been placed in the application file, but the information referred to therein has not been considered. Applicant did not provide translation for the Japanese references.



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Claim Rejections - 35 USC § 112

The following is a quotation of the second paragraph of 35 U.S.C. 112:

The specification shall conclude with one or more claims particularly pointing out and distinctly claiming the subject matter, which the applicant regards as his invention.

Claims 1-18, 20, 22 and 23 are rejected under 35 U.S.C. 112, second paragraph, as being indefinite for failing to particularly point out and distinctly claim the subject matter which applicant regards as the invention.

In claim 1, lines 21 and 42, it is questioned what is recited through use of "should not". Intended claim limitations must be positively recited.

In claim 2, line 8, it appears that "by" should be replaced with -- and --.

Claim Rejections - 35 USC § 102

The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

- (e) the invention was described in-
- (1) an application for patent, published under section 122(b), by another filed in the United States before the invention by the applicant for patent, except that an international application filed under the treaty defined in section 351(a) shall have the effect under this subsection of a national application published under section 122(b) only if the international application designating the United States was published under Article 21(2)(a) of such treaty in the English language; or
- (2) a patent granted on an application for patent by another filed in the United States before the invention by the applicant for patent, except that a patent shall not be deemed filed in the United States for the purposes of this subsection based on the filing of an international application filed under the treaty defined in section 351(a).

Claims 1-4, 7-14, 16, 18, 20, 22 and 23 are rejected under 35 U.S.C. 102(e) as being anticipated by You et al. (6,407,009).

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A method of forming a solution film on an in process substrate by using a dropping section for dropping liquid and an in-process substrate just under said dropping section, maintaining the liquid dropped from said dropping section on said in-process substrate, and relatively moving said in-process substrate or said dropping section, wherein relative movement between said in-process substrate and said dropping section means rotating said substrate and relatively moving said dropping section from an inner periphery of said substrate toward an outer periphery of said substrate; relative movement between said in-process substrate and said dropping section means rotating said substrate and relatively moving said dropping section from an inner periphery of said substrate toward an outer periphery of said substrate for spirally dropping said liquid on said in-process substrate (Col. 9, lines 43-51); rotational frequency w for said substrate is decreased so that a centrifugal force applied to a dropped solution film should not move said dropped solution film in accordance with relative movement of said dropping section from the inner periphery of said in-process substrate toward the outer periphery and feed rate v for said liquid from said dropping section is increased to form a solution film on said in-process substrate (Col. 12, lines 1-5); wherein when said dropping section is positioned to distance r from a center of said in process substrate, feed rate v for said liquid from said dropping section is determined in accordance with rotational frequency w for said in-process substrate so that a constant value is maintained for the product of rotational frequency w and feed rate v of said substrate support; wherein relative movement of said dropping section from an inner periphery to an outer periphery is controlled to move for a specified pitch per

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revolution of said substrate; wherein rotational frequency wo is assumed for an in-process substrate when said dropping section is positioned to radius R on said in-process substrate and feed rate vo is assumed for said liquid when said dropping section is positioned to distance r from a center of said in-process substrate center; and when said substrate is positioned to said distance r, rotational frequency w for said substrate is determined by the product of the square root of (R/r) by wo and feed rate v is determined by vo divided by the square root of (R/r); wherein when said in-process substrate is a disk-shaped substrate with radius R (mm), said dropping section drops liquid at the outmost periphery of said substrate and a rotational frequency (rpm) for said substrate is smaller than the square root of 1,000,000/R (Col. 12, lines 32-57 and Col. 13, lines 60-65); wherein relative movement of said dropping section from the inner periphery of said in-process substrate toward the outer periphery corresponds to the relative movement of said in-process substrate from an approximate center toward the outer periphery; wherein a region including an approximate center of said in-process substrate is used in such a manner that said dropping section moves in a column direction from one end to the other in said region including an approximate center and moves in a row direction outside said region including an approximate center based on the relative movement between said in-process substrate and said dropping section, and said dropping section supplies said in-process substrate with solution at feed rate v' to form a solution film; wherein said feed rate v is set so that it almost equals feed rate v for liquid spirally dropped just outside said region including an approximate center; wherein a region including an approximate center on said in-process substrate prevents

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a solution film from moving due to a centrifugal force applied to a dropped solution film by partially blocking liquid discharged from said dropping section so as not to reach said in-process substrate for droplet amount adjustment; wherein said liquid a solution containing low-dielectric material (Col. 8, line 15); wherein said in-process substrate with said solution film formed thereon is exposed under a pressure lower than a steam pressure at a process temperature for a solvent in said solution film, and said solvent is dried and removed to form a solid layer; wherein said in-process substrate with said solution film formed thereon is exposed to a current of air to dry and remove solvent in said solution film for forming a solid layer (Col. 27, lines 20-23); wherein said in-process substrate is a semiconductor is substrate and said solid layer is selected from at least one of an anti-reflection photosensitive film used for an exposure process, a low-dielectric film wherein said solid layer is a magnetic film or a light absorbent/reactive film.

Claim Rejections - 35 USC § 103

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

Claims 5, 6, 15 and 17 are rejected under 35 U.S.C. 103(a) as being unpatentable over You et al. as applied to claims 1-4, 7-14, 16, 18, 20, 22 and 23 above, and further in view of Akram et al. (5,925,410).

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You et al. does not disclose applying vibrations to the solution to form a solid layer having an almost flat surface.

Akram et al. discloses dispensing a solution in a substrate, spinning the substrate and vibrating the substrate to form a solid layer and planarizing the solid layer (Abstract and Col. 5, lines 59-64).

It would have been within the scope of one of ordinary skill in the art to combine the teachings of You et al. and Akram et al. to enable formation of the solid layer and further the vibrations eliminate voids and/or gaps in the dispensed material.

Choice of a particular disk diameter and rotational frequency would have been a matter of routine optimization. See MPEP 2144.05.

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Michelle Estrada whose telephone number is (703) 308-0729. The examiner can normally be reached on Monday through Friday.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Olik Chaudhuri can be reached on 703-306-2794. The fax phone numbers for the organization where this application or proceeding is assigned are 703-308-7722 for regular communications and 703-308-7724 for After Final communications.

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Any inquiry of a general nature or relating to the status of this application or proceeding should be directed to the receptionist whose telephone number is 703-308-0956.

MEstrada

November 27, 2002

Olik Chaudhurl

Supervisory Patent Examiner Technology Center 2800